

LED Drivers for LCD Backlights White LED Driver for large LCD Panels (DCDC Converter type)

BD93942F

General Description

BD93942F is a high efficiency driver for white LEDs and designed for large LCDs. These ICs are built-in a boost DCDC converters that employ an array of LEDs as the light source. BD93942F have some protect function against fault conditions, such as the over-voltage protection (OVP), the over current limit protection of DCDC (OCP), the short circuit protection (SCP), the open detection of LED string. Therefore BD93942F are available for the fail-safe design over a wide range output voltage.

Key Specification

- Operating power supply voltage range: 9.0V to 35.0V
- LED minimum current
- LED maximum current:
- Oscillator frequency: 150kHz (RT=100kΩ)
- Operating Current:

Typical Application Circuit

3.7mA (Typ.) ure range: -40°C to +85°C

30mA

150mA

Operating temperature range:

Applications

TV, Computer Display, Notebook, LCD Backlighting

Package	W(Typ.) x D(Typ.) x H(Max.)
SOP16	10.00mm x 6.20mm x 1.71mm

Features

- 4ch LED constant current driver and DC/DC converter
 - Maximum LED Current: 150mA
 - LED Feedback Voltage: 0.45V (@ILED=150mA) so lower heat. Adjustable Feed Back Voltage by following LED Current setting.
 - ±2% LED current accuracy (ADIM=2.5V, when each LED is set to 100mA)
 - Analog current (Linear) dimming at ADIM pin
 - LED pin rating 60V
 - Individual detection and individual LED OFF for both open and short circuits
 - Built-in ISET pin short-circuit protection circuit
 - FET's Gate (N pin) is driven by 5.8V swing
 - Built-in Vout discharge circuit for shutdown
 - Built-in Vout overvoltage protection (OVP) / reduced voltage protection (SCP) circuit
 - SOP16 package



Figure 1. SOP16

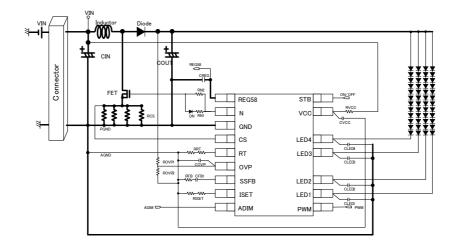


Figure 2. Typical Application Circuit

OProduct structure : Silicon monolithic integrated circuit OThis product has not designed protection against radioactive rays

Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit	
VCC	36	V	
STB, ADIM, OVP, PWM	36	V	
LED1 to 4	60	V	
REG58, CS, N, ISET, SSFB, RT	7	V	
Pd	0.62 *1	W	
Topr	-40 to +85	°C	
Tstg	-55 to +150	°C	
Tjmax	150	°C	
	VCC STB, ADIM, OVP, PWM LED1 to 4 REG58, CS, N, ISET, SSFB, RT Pd Topr Tstg	VCC 36 STB, ADIM, OVP, PWM 36 LED1 to 4 60 REG58, CS, N, ISET, SSFB, RT 7 Pd 0.62 *1 Topr -40 to +85 Tstg -55 to +150	

*1 Ta = 25°C or more, diminished at -5mW/°C in the case of SOP16 (when 1-layer / 70.0 mm x 70.0 mm x 1.6 mm board is mounted)

Operating Ratings

Parameter	Symbol	Limits	Unit	
VCC supply voltage	VCC	9.0 to 35.0	V	
Min. output current of LED1 to 4	ILED_MIN	30	mA *1	
Max. output current of LED1 to 4	ILED_MAX	150	mA *1,2	
ADIM input voltage1 (use ADIM function)	VADIM1	0.2 to 2.7 (normal op.) 1.0 to 2.7 (start up)	V *3	
ADIM input voltage1 (don't use ADIM function)	VADIM2	REG58 to 35.0	V	
DC/DC oscillation frequency	Fsw	100 to 800	kHz	
Min. on-duty time for PWM light modulation	PWM_MIN	30	μs	

*1 The amount of current per channel.

*2 If LED makes significant variations in its reference voltage, the driver will increase power dissipation, resulting in a rise in package temperature.

To avoid this problem, design the board with thorough consideration given to heat radiation measures.

*3 To avoid unused LED pin's misdetection, set ADIM within 1.0V to 2.7V at start up stage. After unused LED pin's detection, set ADIM within 0.2V to 2.7V in normal operation.

Pin Configuration

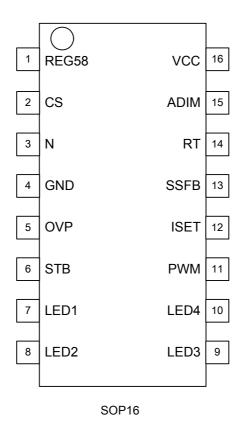
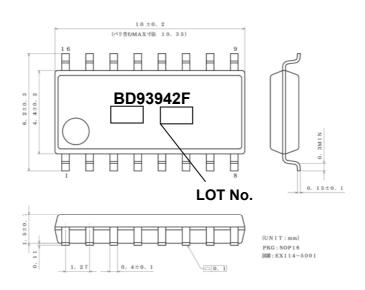


Figure 3. Pin Configuration

Marking diagram and physical dimension

SOP16



Electrical Characteristics (Unless otherwise noted, Ta = 25°C, VCC=24V)

Deveneder	Cumhal		Limit		11	Condition	
Parameter	Symbol	Min. Typ. N		Max.	Unit	Condition	
[Whole Device]						1	
Circuit current while in operation	ICC	-	3.7	7.4	mA	STB=3V,PWM=3V, RT=100kΩ	
Circuit current while in standby	ISTB	-	40	80	μA	STB=0V	
[REG58 Block]							
REG58 Output Voltage	REG58	5.742	5.8	5.858	V	IO=0mA	
REG58 available current	IREG58	15	-	-	mA		
[UVLO Block]							
UVLO release voltage	VUVLO_VCC	6.5	7.5	8.5	V	VCC=SWEEP UP	
UVLO hysteresis voltage	VUHYS_VCC	150	300	600	mV	VCC=SWEEP DOWN	
[DC/DC Block]						1	
Error amp. Reference voltage	VLED	0.425	0.450	0.475	V	ISET=50kΩ, ADIM=2.5V ILED=150mA	
Oscillation frequency	fsw	142.5	150.0	157.5	kHz	RT=100kΩ	
Max. duty cycle per output of N pin	DMAX	83	90	97	%	RT=100kΩ	
On resistance on N pin source side	RONH	-	4	8	Ω	ION=-10mA	
On resistance on N pin sink side	RONL	-	3	6	Ω	ION=10mA	
SSFB pin source current (at soft start)	ISSSO	-13.0	-10.0	-7.0	uA	SSFB=2V	
SSFB sink current	IFBSI	50	100	150	μA	LED=2.0V,SSFB=1.0V	
SSFB source current	IFBSO	-150	-100	-50	μA	LED=0V, SSFB=1.0V	
Over current detection voltage	VCS	0.40	0.45	0.50	V	CS=SWEEP UP	

BD93942F

Electrical Characteristics (Unless otherwise noted, Ta = 25°C, VCC=24V)

Devenenciev	Cumhal		Limit		11	O a w aliti a w	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
[DC/DC Protection Block]							
Overvoltage protection detection voltage	VOVP	2.7	3.0	3.3	V	OVP=SWEEP UP	
Overvoltage protection detection hysteresis voltage	VOVP_HYS	50	100	200	mV	OVP=SWEEP DOWN	
Short circuit protection detection voltage	VSCP	0.04	0.10	0.25	V	OVP=SWEEP DOWN	
[LED Driver Block]							
LED pin current accuracy 1	dILED1	-2	-	2	%	ILED=100mA, (ADIM=2.5V,ISET=75kΩ)	
LED pin current accuracy 2	dILED2	-3.2	-	3.2	%	ILED=70mA, (ADIM=1.75V,ISET=75kΩ)	
LED pin current accuracy 3	dILED3	-4.6	-	4.6	%	ILED=50mA, (ADIM=1.25V,ISET=75kΩ)	
LED pin current accuracy 4	dILED4	-8	-	8	%	ILED=30mA, (ADIM=0.75V,ISET=75kΩ)	
LED pin current accuracy 5	dILED5	-3	-	3	%	ILED=100mA, (ADIM=7V,ISET=75kΩ)	
LED pin Leakage Current	ILLED	-2.5	-	2.5	μA	LED=60V	
LED open detection voltage	VOPEN	0.05	0.2	0.285	V	LED=SWEEP DOWN	
LED short detection voltage	VSHORT	4	5	6	V	LED=SWEEP UP	
ADIM pin Input Current	ILADIM	-2.5	-	2.5	μA	ADIM=3V	
[STB Block]							
STB pin high-level voltage	STBH	2	-	35	V	STB=SWEEP UP	
STB pin low-level voltage	STBL	-0.3	-	0.8	V	STB=SWEEP DOWN	
STB pin pull-down resistance	RSTB	500	1000	1500	kΩ	STB=3.0V	
[PWM Block]							
PWM pin high-level voltage	PWMH	2	-	35	V	PWM=SWEEP UP	
PWM pin low-level voltage	PWML	-0.3	-	0.8	V	PWM= SWEEP DOWN	
PWM pin pull-down resistance	RPWM	180	300	420	kΩ	PWM=3.0V	
[Failure Indication Block (Open Dr	ain)]						
AUTO Timer	tAUTO	-	0.655	-	sec	RT=75kΩ	
Abnormal Detection Timer	tCP		20		ms	RT=75kΩ	

Pin Descriptions (SOP16)

Pin No	Pin Name	In/Out	Function	Rating [V]
1	REG58	Out	Power supply for N pin	-0.3 to 7
2	CS	In	DC/DC output current detection and OCP detection pin	-0.3 to 7
3	N	Out	DC/DC switching output pin	-0.3 to 7
4	GND	-	Ground pin	-
5	OVP	In	Overvoltage protection detection pin	-0.3 to 36
6	STB	In	Enable pin	-0.3 to 36
7	LED1	Out	Output pin 1 for LED	-0.3 to 60
8	LED2	Out	Output pin 2 for LED	-0.3 to 60
9	LED3	Out	Output pin 3 for LED	-0.3 to 60
10	LED4	Out	Output pin 4 for LED	-0.3 to 60
11	PWM	In	External PWM light modulation signal input pin for LED1-4	-0.3 to 36
12	ISET	Out	LED current setting resistor connection pin	-0.3 to 7
13	SSFB	In/Out	Soft start setting, Loop compensation setting pin	-0.3 to 7
14	RT	Out	DC/DC drive frequency setting resistor connection pin.	-0.3 to 7
15	ADIM	In	Analog dimming DC voltage input pin -0.3	
16	VCC	In	Power supply pin -0.3 t	

Pin ESD Type

REG58 / N /GND/ CS	ADIM	SSFB	
LED1~4	RT	STB	
		STB 	
PWM	ISET	OVP	

Figure 5. Pin ESD Type

Block Diagram

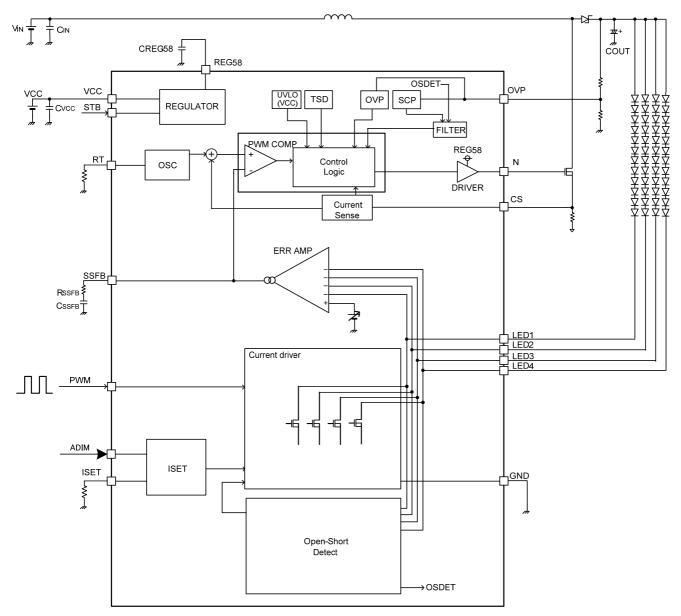


Figure 6. Block Diagram

Typical Performance Curve

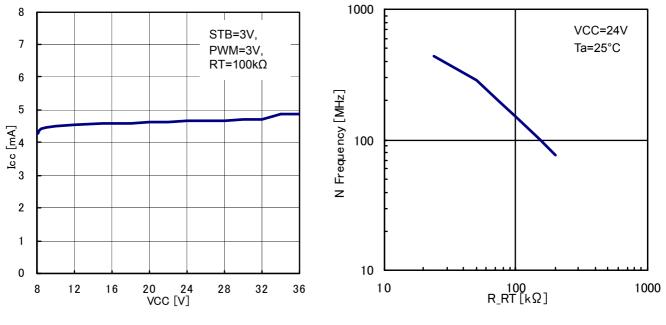
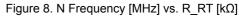


Figure 7. Operating Current (ICC) [mA] vs. VCC[V]



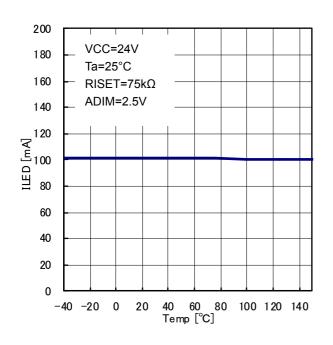


Figure 9. LED Current (ILED) [mA] vs. Temp [°C]

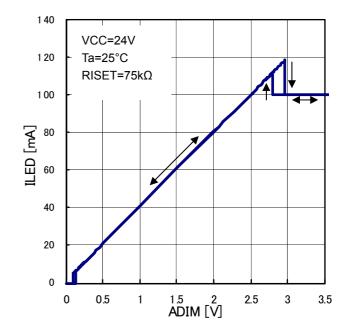


Figure 10. LED Current (ILED) [mA] vs. ADIM[V],

Pin Function

oREG58 (1pin)

The REG58 pin is used in the DC/DC converter driver block to output 5.8V power. The maximum operating current is 15mA. Using the REG58 pin at a current higher than 15mA can affect the N pin output pulse, causing the IC to malfunction and leading to heat generation of the IC itself. To avoid this problem, it is recommended to make load setting to the minimum level.

Please place the ceramic capacitor connected to REG58 pin (2.2µF to 10µF) closest to REG58-GND pin.

oCS (2pin)

The CS pin has the following two functions:

1. DC/DC current mode current feedback function

Current flowing through the inductor is converted into voltage by the current sensing resistor RCS connected to the CS pin and this voltage is compared with voltage set with the error amplifier to control the DC/DC output voltage.

2. Inductor current limit function

The CS pin also incorporates the over current protection (OCP) function. If the CS pin voltage reaches 0.45V (Typ.) or more, switching operation will be forcedly stopped.

∘*N (3pin)*

The N pin is used to output power to the external NMOS gate driver for the DC/DC converter in the amplitude range of approx. 0 to REG58. ON resistances is 4.0Ω(typ.) in sorrce (H side), 3.0Ω(typ.) in sink (L side).

Frequency setting can be made with a resistor connected to the RT pin. For details of frequency setting, refer to the description of the RT pin.

oGND (4pin)

Ground of the IC.

• OVP (5pin)

The OVP pin is an input pin for over-voltage protection and short circuit protection of DC/DC output voltage. If over-voltage is detected, the OVP pin will stop the DC/DC converter conducting step-up operation. When the short circuit protection (SCP) function is activated, the DC/DC converter will stop operation, and then the timer will start counting. When the timer completes counting the preset period of time, the LED drivers are stopped.

The OVP pin is of the high impedance type and involves no pull-down resistor, resulting in unstable potential in the open-circuited state. To avoid this problem, be sure to make input voltage setting with the use of a resistive divider or otherwise.

oSTB (6pin)

The STB pin is used to make setting of turning ON and OFF the IC and allowed for use to reset the IC from shutdown. Note: The IC state is switched (i.e., the IC is switched between ON and OFF state) according to voltages input in the STB

pin. Avoid using the STB pin between two states (0.8 to 2.0V).

When STB signal is set to Low or High, change it from Low to High after REG58 output completely discharges.

oLED1 – LED4 (7pin – 10pin)

The LED1 to 4 pins are used to output constant current to LED drivers. Current value setting can be made by connecting a resistor to the ISET pin.

For the current value setting procedure, refer to the description of "ISET pin".

If any of the LED pins is put in an erroneous state (e.g. short circuit mode, open circuit mode, or ground short circuit mode), the relevant protection function will be activated.

This IC is detected automatically that it is an unused channel by asssuming the LED terminal to be connected to GND before start up.

• PWM (11pin)

The PWM pin is used to turn ON and OFF LED drivers. Light can be modulated by changing the duty cycle through the direct input of a PWM light modulation signal. The high and low voltage levels of PWM pin is as listed in the table below:

State	PWM Voltage
LED ON state	PWM= 2.0V to 35V
LED OFF state	PWM= -0.3V to 0.8V

∘ISET (12pin)

The ISET pin is an output current setting resistor. Output current ILED varies in inverse proportion to resistance. The relation between output current ILED and the resistance of ISET pin connection resistor RISET is given by the following equation:

$$I_{LED}[mA] = \frac{3000}{R_{ISET}[k\Omega]} \times V_{ADIM}[V]$$
(ADIM=0.2V to2.7V)
$$I_{LED}[mA] = \frac{7500}{R_{ISET}[k\Omega]}$$
(ADIM>4V to 35V)

Output current setting should be made in the range of 30mA to 150mA.

It prepares automatically to suitable LED feedback voltage that can output LED current set by ISET pin.

In short LED feedback voltage is dropped when the LED current is small and the IC heating is held automatically.

In case of a large current is needed, raise the LED pin feedback voltage. And it adjusts automatically to LED pin voltage that can be flow large LED current.

The calculation is as below.

 $VLED = 3 \times I_{LED} [A] [V] (ILED > 117mA)$ VLED = 0.35[V](typ) (ILED < 117mA)

The LED feedback voltage (VLED) is clamped to 0.35V (typ.) when the LED current (ILED) is less than 117mA.

ADIM input range is from 0V to 35V. And the range which the LED currents change with linearity is from 0.2V to 2.7V. When it reaches under VISET×0.90V(typ.), the LED current is off to prevent from passing a large current to the LED pin when the RISET is shorted and the ISET pin is shorted to the GND. And as the ISET pin returns to a normal state, the LED current returns.

• SSFB (13pin)

The SSFB pin is used to make setting of soft start time and duty for soft start, and DC/DC current mode control error amplifier. It performs constant current charge of 10uA to the external capacitor connected to SSFB terminal, which enables soft-start of DC/DC converter.

The SSFB pin detects the voltages of LED pins (1 to 4) and controls inductor current so that the pin voltage of the LED located in the row with the highest Vf will come to $0.45V(ADIM=2.5V,ISET=50k\Omega,ILED=150mA)$. As a result, the pin voltages of other LEDs become higher by Vf variation. After completion of soft start, the SSFB pin is put into the high-impedance state with the PWM signal being in the low state, thus maintaining the SSFB voltage.

Since the LED protection function (OPEN/SHORT detection) works when it turns to the LED feedback mode.

oRT (14pin)

The RT pin is used to connect a DC/DC frequency setting resistor. DC/DC drive frequency is determined by connecting the RT resistor.

ODrive frequency vs. RT resistance (Ideal)

D	_	15000	$[k\Omega]$	
$\mathbf{\Lambda}_{RT}$	_	$f_{SW}[kHz]$	[K32]	

When RT is $100k\Omega$, Fsw is 150kHz(typ.). However, drive frequency setting should be made in the range of 100 kHz to 800 kHz.

o ADIM (15pin)

ADIM pin is for analog dimming. Output current is proportionality with input voltage. Basically, ADIM pin assumes the voltage inputted externally using high accuracy of resistive divider and etc., IC internally is in OPEN (High impedance) condition. <u>Cannot use in an OPEN condition</u>.

If you don't use analog dimming, please connect pull-up resistor to over 5V (for example REG58).

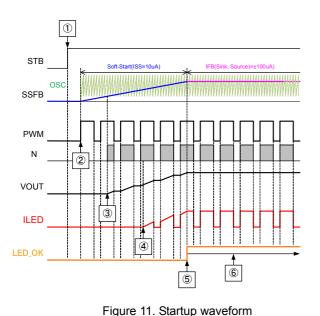
• VCC (16pin)

The VCC pin is used to supply power for the IC in the range of 9 to 35V.

If the VCC pin voltage reaches 7.5V (Typ.) or more, the IC will initiate operation. If it reaches 7.2V (Typ.) or less, the IC will be shut down.

Startup operation and soft start (SSFB) capacitance setting

The following section describes the sequence for the startup of this IC.



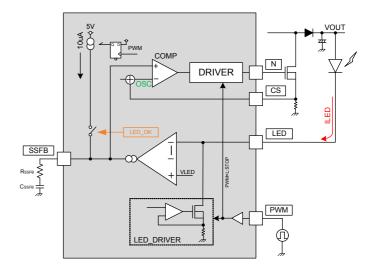


Figure 12. Circuit behavior at startup

ODescription of startup sequence

- (1) Set the STB and PWM pin to "ON".
- (2) Set all systems to "ON", SSFB charge will be initiated.
- (3) Since the SSFB pin reach the lower limit of the internal sawtooth wave of the IC, the DC/DC converter operates to start VOUT voltage rising.
- (4) The Vout voltage continues rising to reach a voltage at which LED current starts flowing.
- (5) When the LED current reaches the set amount of current, the startup operation is completed.
- (6) After that, conduct normal operation following the feedback operation sequence with the LED pins. If the SSFB pin sink/source current is ±100uA, the LED protection function will be activated.

OSSFB capacitance setting procedure

As aforementioned, this IC stops DC/DC converter when the PWM pin is set to Low level and conducts step-up operation only in the section in which the PWM pin is maintained at High level. Consequently, setting the PWM duty cycle to the minimum will extend the startup time. The startup time also varies with application settings of output capacitance, LED current, output voltage, and others.

Startup time at minimum duty cycle can be approximated according to the following method:

Make maeasurement of VOUT startup time with a 100% duty cycle, first. Take this value as "Trise100".

The startup time "Trise_min" for the relevant application with the minimum duty cycle is given by the following equation.

$$T_{rise_\min} = \frac{T_{rise_100}[Sec]}{Min_Duty[ratio]} [Sec]$$

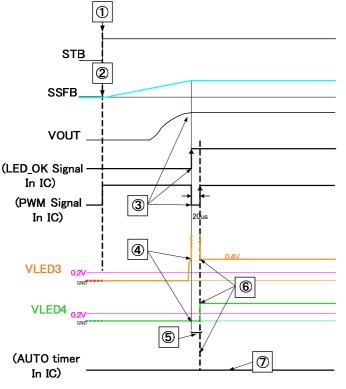
However, <u>since this calculation method is just for approximation, use it only as a guide.</u> Assuming that the SSFB pin voltage is VSSFB, the time is given by the following equation:

$$T_{SSFB} = \frac{C_{SSFB}[F] \times VSSFB[V]}{10[\mu A]} \quad [Sec]$$

As a result, it is recommended to make SSFB capacitance setting so that "T_{SSFB}" will be greater than "Trise_min"</sub>

About unused LED terminal automatic detecting function

This IC is detected automatically that it is an unused channel by asssuming the LED terminal to be OPEN at starting. It explains the sequence.



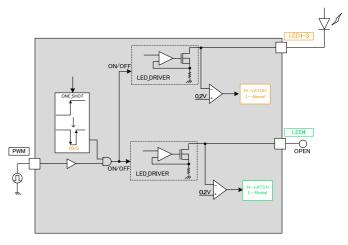


Figure 14. Block diagram

Figure 13. Timming chart

Sequence;

- ① STB=PWM=ON
- 2 All systems are ON and SSFB starts charging.

③ When the output voltage is boosted enough, and enough current flows through the LED, LED_OK signal is switched in the IC. PWM=L from the Rise timing of this signal for about 20us

④ During this PWM=L period, LED pins with LED connections' output voltage becomes 0.2V and above, where as unused LED pins are below 0.2V.

(5) During this time, determination on whether the LED pins are 0.2V above/below is done.

(6) After the determination, unused LED pins are pulled up to 5V.

⑦The AUTO timer don't count.

LED current setting

Setting of LED output current "ILED" can be made by connecting a resistor RISET to the ISET pin.

ORISET vs. ILED current relation equation

$$R_{ISET} = \frac{7500}{I_{LED}[mA]} [k\Omega] \qquad (ADIM=2.5V)$$

However, LED current setting should be made in the range of 30mA to 150mA.

[Setting example]

To set ILED current to 100mA, RISET resistance is given by the following equation:

$$R_{ISET} = \frac{7500}{I_{LED}[mA]} = \frac{7500}{100[mA]} = 75 \quad [k\Omega]$$

DC/DC converter drive frequency setting

DC/DC converter drive frequency is determined by making RT resistance setting.

ODrive frequency vs. RT resistance (ideal) relation equation

$$R_{RT} = \frac{15000}{f_{SW}[kHz]} \quad [k\Omega]$$

where fsw = DC/DC converter oscillation frequency [kHz]

This equation has become an ideal equation without any correction item included. For accurate frequency settings, thorough verification should be performed on practical sets.

[Setting example]

To set DC/DC drive frequency "fsw" to 200 kHz, RRT is given by the following equation:

$$R_{RT} = \frac{15000}{f_{sw}[kHz]} = \frac{15000}{200[kHz]} = 75 \quad [k\Omega]$$

VOUT

Figure 15. OVP/SCP setting example

OVP

COVP

R2

OVP/SCP Settings

OVP pin is DC/DC output voltage's over voltage protection and short circuit protection input pin. OVP pin is a high impedance pin with no pull down resistor. Thus, at OPEN state please set the voltage input settings using voltage dividing resistor and such.

Protection Name	Detection Pin	Detection Condition	Cancellation Condition	Timer Operations	Protection Type
OVP	OVP	OVP>3.0V	OVP<2.9V	No	DCDC stops during detection
SCP	OVP	OVP<0.1V	OVP>0.1V	Yes	All latch

OVP COMP

SCP COM

2.9V/3.0V

0.1V

Respective OVP pin protection conditions are as below

OVP Detection Setting

VOUT abnormally increase, voltage detected by OVP, VOVPDET. R1,R2 settings are as follows

$$R1 = R2[k\Omega] \times \frac{(VOVP_{DET}[V] - 3.0[V])}{3.0[V]} \quad [k\Omega]$$

OVP Cancellation Setting

R1,R2 set from above equation, OVP cancellation voltage VOVP_{CAN} equals to

$$VOVP_{CAN} = 2.9V \times \frac{(R1[k\Omega] + R2[k\Omega])}{R2[k\Omega]} \quad [V]$$

SCP Detection Setting

When R1,R2 are set using values obtained above, SCP voltage setting is VSCP_{DET} is as follows

$$VSCP_{DET} = 0.1V \times \frac{(R1[k\Omega] + R2[k\Omega])}{R2[k\Omega]} \quad [V]$$

[Setting Example]

VOUT at normal operation 56V, OVP detection voltage VOVP_{DET}=68V, R2=10k, R1 is as follows

$$R1 = R2[k\Omega] \times \frac{(VOVP_{DET}[V] - 3.0[V])}{3.0[V]} = 10[k\Omega] \times \frac{(68[V] - 3[V])}{3[V]} = 216.7 \quad [k\Omega]$$

When R1, R2 are set at these values, OVP cancellation voltage, VOVP_{CAN}

$$VOVP_{CAN} = 2.9[V] \times \frac{(R1[k\Omega] + R2[k\Omega])}{R2[k\Omega]} = 2.9[V] \times \frac{10[k\Omega] + 216.7[k\Omega]}{10[k\Omega]}[V] = 65.7 \quad [V]$$

In addition, at this R1, R2, SCP detection voltage

$$VSCP_{DET} = 0.1[V] \times \frac{(R1[k\Omega] + R2[k\Omega])}{R2[k\Omega]} = 0.1[V] \times \frac{10[k\Omega] + 216.7[k\Omega]}{10[k\Omega]}[V] = 2.27 \quad [V]$$

To select DC/DC components, give consideration to IC variations as well as individual component variations, and then conduct thorough verification on practical systems.

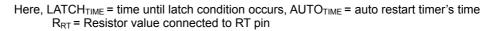
Timer Latch Time Setting

This IC has a built-in timer latch counter. Timer latch time is set by counting the clock frequency which is set at the RT pin. After abnormal detection time passes, AUTO timer starts, it let IC auto-restart after constant setting time.

Timer Latch Time

When various abnormal conditions happen, counting starts from the timing, latch occurs after below time has passed. Furthermore, even if PWM=L, if abnormal condition continues, timer count will not reset.

$$LATCH_{TIME} = 2^{12} \times \frac{R_{RT}}{1.5 \times 10^{10}} = 4096 \times \frac{R_{RT}[k\Omega]}{1.5 \times 10^7}[s]$$
$$AUTO_{TIME} = 2^{17} \times \frac{R_{RT}}{1.5 \times 10^{10}} = 131072 \times \frac{R_{RT}[k\Omega]}{1.5 \times 10^7}[s]$$



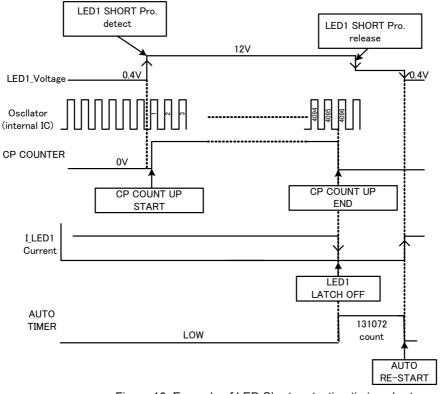


Figure 16. Example of LED Short protection timing chart

[Setting Example]

Timer latch time when RT=75kohm

$$LATCH_{TIME} = 4096 \times \frac{R_{RT}[k\Omega]}{1.5 \times 10^7} = 4096 \times \frac{75[k\Omega]}{1.5 \times 10^7} = 0.02[s]$$
$$AUTO_{TIME} = 131072 \times \frac{R_{RT}[k\Omega]}{1.5 \times 10^7} = 131072 \times \frac{75[k\Omega]}{1.5 \times 10^7} = 0.655[s]$$

OCP Settings/DCDC Components' Current Capacity Selection Method

One of the function of CS pin - when its pin voltage>0.45 it stops the DCDC. Thus, RCS resistor value need to be checked after the peak current flow through the inductor is calculated. Furthermore, DCDC external components' current capacity needs to be greater than peak current flowing through this inductor.

(Inductor peak current lpeak calculation method)

Firstly, ripple voltage which occurs at the CS pin is decided depending on the DCDC application conditions. The conditions when made as below;

Output voltage=VOUT[V] LED total current=IOUT[A] DCDC input voltage=VIN[V] DCDC efficiency =n[%] Total required average input current IIN:

$$I_{IN} = \frac{V_{OUT}[V] \times I_{OUT}[A]}{V_{IN}[V] \times \eta[\%]} \quad [A]$$

Inductor ripple current IL[A] which occurs at inductor L[H] during DCDC drive operation with switching frequency=fsw[Hz] is as follows

$$\Delta IL = \frac{(V_{OUT}[V] - V_{IN}[V]) \times V_{IN}[V]}{L[H] \times V_{OUT}[V] \times f_{SW}[Hz]} \quad [A]$$

Therefore, IL's peak current lpeak can be calculated using below equation

$Ipeak = I_{IN}[A] + \frac{\Delta IL[A]}{2}$	[<i>A</i>]···(1)
--	--------------------

(Resistor RCS connected to CS pin selection method)

This Ipeak flows in RCS and generates voltage. (refer to time chart diagram on the right). This voltage value, VCSpeak can be calculated as below

$$VCS_{peak} = Rcs \times Ipeak \quad [V]$$

This VCSpeak when reach 0.45V, will stop the DCDC output. Thus when selecting RCS value, below condition needs to be met.

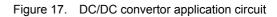
$$Rcs[\Omega] \times Ipeak[A] < 0.45[V]$$

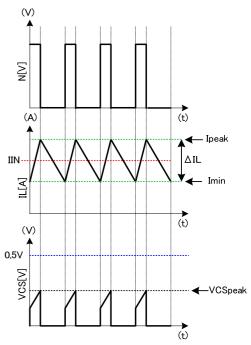
(DCDC Components' Current Capacity Selection Method)

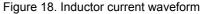
When OCP reach detection voltage CS=0.45V, locp current

$$I_{OCP} = \frac{0.45[V]}{Rcs[\Omega]} \quad [A]\cdots(2)$$

VIN TIL fsw fsw CS Rcs DCDC_GND







Ipeak current (1), I_{OCP} current (2), and components' MAX current capacity needs to satisfy the following

$$I_{\it peak}$$
 < $I_{\it OCP}$ < Rated current of components

Above condition needs to be satisfied when selecting DCDC application parts eg. FET, inductor, diode etc. Furthermore, continuous mode is recommended for normal DCDC applications. Inductor's ripple current MIN limit value, Imin becoming

$$\operatorname{Im} in = I_{IN}[A] - \frac{\Delta IL[A]}{2}[A] > 0$$

Is a condition to be met. If this is not met, it is called discontinuous mode.

[Setting Example]

Output voltage=VOUT[V]=56V LED total current=IOUT[A]=100mA×4ch=0.40A DCDC input voltage=VIN[V]=14V DCDC efficiency=n[%]=90% Total required average input current IIN:

$$I_{IN}[A] = \frac{V_{OUT}[V] \times I_{OUT}[A]}{V_{IN}[V] \times \eta[\%]} = \frac{56[V] \times 0.40[A]}{14[V] \times 90[\%]} = 1.78 \quad [A]$$

When, DCDC switching frequency =fsw[Hz]=200kHz Inductor L[H]=33uH, Inductor ripple current Δ IL[A]:

$$\Delta IL = \frac{(V_{OUT}[V] - V_{IN}[V]) \times V_{IN}[V]}{L[H] \times V_{OUT}[V] \times f_{SW}[Hz]} = \frac{(56[V] - 14[V]) \times 14[V]}{33 \times 10^{-6}[H] \times 56[V] \times 200 \times 10^{3}[Hz]} = 1.59 \quad [A]$$

Thus, IL peak current Ipeak becomes

RCS resistor value when set at 0.10hm

$$VCS_{peak} = Rcs \times Ipeak = 0.10[\Omega] \times 2.58[A] = 0.258 \quad [V] < 0.45V \quad \text{...RCS resistor consideration}$$

and satisfy the condition.

In addition, OCP detection current I_{OCP} at this time is

$$I_{OCP} = \frac{0.45[V]}{0.1[\Omega]} = 4.5 \quad [A]$$

If parts used (FET,INDUCTOR, DIODE etc)'s current capacity<5A,

$$I_{peak} < I_{OCP} < \text{Rated current of components} = 2.58[A] < 4.5[A] < 5[A]$$

···DCDC current capacity consideration

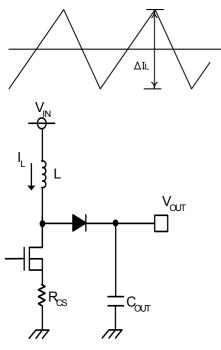
Thus, there is no problem of parts selection as the above condition is satisfied. In addition, IL ripple current minimum limit Imin is

$$\operatorname{Im} in = I_{IN}[A] - \frac{\Delta IL[A]}{2}[A] = 1.78[A] - 0.795[A] = 0.985[A] > 0$$

Thus, will not become discontinuous mode.

To select DC/DC components, give consideration to IC variations as well as individual component variations, and then conduct thorough verification on practical systems.

Selection of inductor L



The value of inductor has significant influence on the input ripple current. As shown by Equation (1), the larger the inductor and the higher the switching frequency, the inductor ripple current Δ IL becomes increasingly lower.

$$\Delta IL = \frac{(V_{OUT} - V_{IN}) \times V_{IN}}{L \times V_{OUT} \times f_{SW}} [A] \qquad (1)$$

Expressing efficiency as shown by Equation (2), peak input current is given as Equation (3).

$$\eta = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times I_{IN}} \qquad \cdots \qquad (2)$$

$$IL_{MAX} = I_{IN} + \frac{\Delta IL}{2} = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times \eta} + \frac{\Delta IL}{2} \qquad \cdots \qquad (3)$$

where, L: Reactance value [H],

 V_{OUT} : DC/DC output voltage [V], V_{IN} : Input voltage [V], I_{OUT} : Output load current (total output current) [A], I_{IN} : Input current [A], and F_{SW} : Oscillation frequency [Hz]

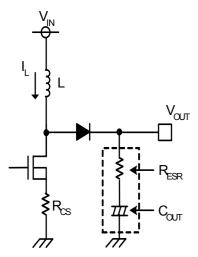
Figure 19. Inductor current waveform and diagram

Note: If a current in excess of the rated current of the inductor applies to the coil, the inductor will cause magnetic saturation, resulting in efficiency degradation.

Select an inductor with an adequate margin so that peak current will not exceed the rated current of the inductor.

Note: To reduce power dissipation from and increase efficiency of inductor, select an inductor with low resistance component (DCR or ACR).

Selection of output capacitor COUT



Select a capacitor on the output side taking into account the stability region of output voltage and equivalent series resistance necessary to smooth ripple voltage. Note that higher output ripple voltage may result in a drop in LED pin voltage, making it impossible to supply set LED current. The output ripple voltage ΔV_{OUT} is given by Equation (4).

$$\Delta V_{OUT} = ILMAX \times R_{ESR} + \frac{1}{C_{OUT}} \times \frac{I_{OUT}}{\eta} \times \frac{1}{f_{SW}} [V] \quad \cdot \quad \cdot \quad \cdot \quad (4)$$

where $R_{ESR} =$ Equivalent series resistance of C_{OUT} .

Note: Select capacitor ratings with an adequate margin for output voltage. Note: To use an electrolytic capacitor, an adequate margin should be provided for permissible current. Particularly to apply PWM light modulation to LED, note that a current higher than the set LED current transiently flows.

Figure 20. Output capacitor diagram,

Selection of switching MOSFET transistors

There will be no problem for switching MOSFET transistors having absolute maximum rating higher than rated current of the inductor L and VF higher than " C_{OUT} breakdown voltage + Rectifier diode". However, to achieve high-speed switching, select transistors with small gate capacity (injected charge amount).

Note: Rated current larger than over current protection setting current is recommended.

Note: Selecting transistors with low on resistance can obtain high efficiency.

Selection of rectifier diodes

Select Schottky barrier diodes having current capability higher than the rated current of the inductor L and inverse breakdown voltage higher that C_{OUT} breakdown voltage, particularly having low forward voltage VF.

BD93942F

Phase Compensation Setting Procedure

DC/DC converter application for current mode control includes one each of pole f_p (phase delay) by CR filer consisting of output capacitor and output resistor (i.e., LED current) and zero (phase lead) f_z by the output capacitor and capacitor ESR. Furthermore, the step-up DC/DC converter includes RHP zero " f_{ZRHP} " as the second zero. Since the RHP zero has phase delay

 (-90°) characteristics like the pole, the crossover frequency f_c should be set to not more than RHP zero

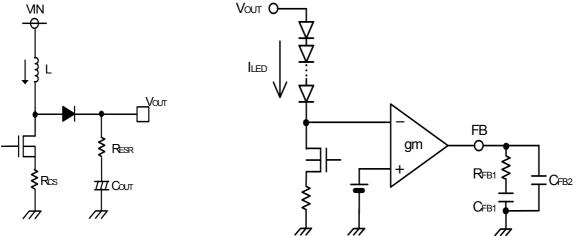


Figure 21. Output stage and error amplifier diagram

i. Find pole fp and RHP zero fZRHP of DC/DC converter.

$$f_p = \frac{I_{LED}}{2\pi \times V_{OUT} \times C_{OUT}} [Hz] \qquad \qquad f_{ZRHP} = \frac{V_{OUT} \times (1-D)^2}{2\pi \times L \times I_{LED}} [Hz]$$

Where I_{LED} = Total LED current [A],

$$D = \frac{V_{OUT} - V_{IN}}{V_{OUT}}$$

ii. Find phase compensation to be inserted in the error amplifier. (Set f_c to 1/5 of f_{ZRHP} .)

$$R_{FB1} = \frac{f_{RHZP} \times R_{CS} \times I_{LED}}{5 \times f_{p} \times gm \times V_{OUT} \times (1-D)} [\Omega]$$

$$C_{FB1} = \frac{1}{2\pi \times R_{FB1} \times f_C} = \frac{5}{2\pi \times R_{FB1} \times f_{ZRHP}} [F]$$

where

iii. Find zero used to compensate ESR (R_{ESR}) of C_{OUT} (electrolytic capacitor).

$$C_{FB2} = \frac{R_{ESR} \times C_{OUT}}{R_{FB1}} [F]$$

 $gm = 4.0 \times 10^{-4} [S]$

Note: Even if a ceramic capacitor (R_{ESR} of the order of milliohms) for C_{OUT} , it is recommended to insert C_{FB2} for stable operation.

To improve transient response, it is necessary to increase R_{FB1} and reduce C_{FB1} . However, this improvement reduces a phase margin. To avoid this problem, conduct thorough verification, including variations in external components, on practical systems.

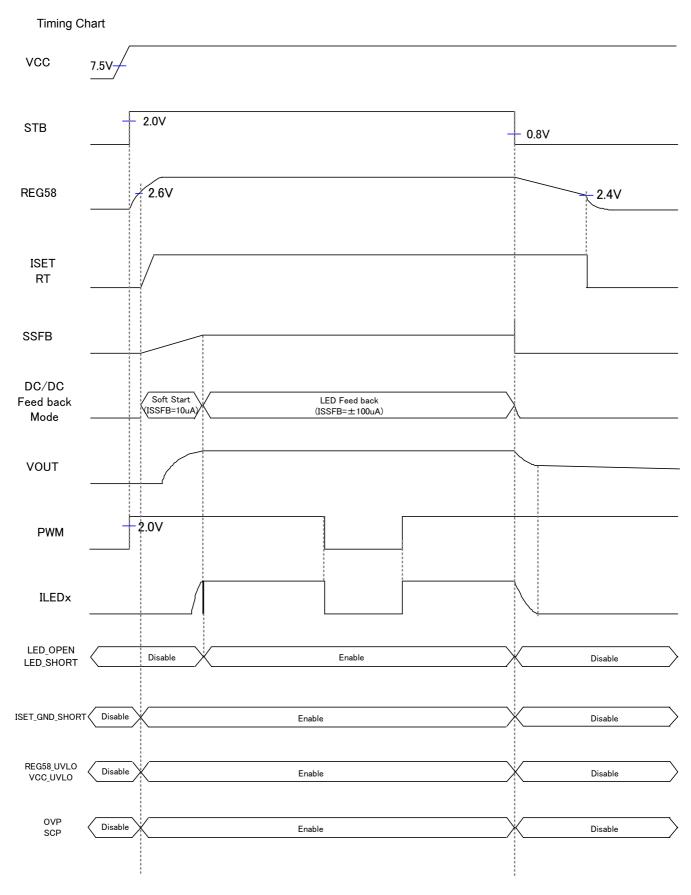


Figure 22. Timing chart

List of Protect Function (typ condition)

Protection	Detection Pin	Detection Conditions			Cancellation	Timer	Droto offen Turne
Name		Detection pin	PWM	LED_OK	Conditions	Timer	Protection Type
LED OPEN	LEDx	LEDx < 0.2V	Н	After LED_OK	LEDx > 0.2V	2 ¹² count	Immediately Auto-Restart after detection (Judge periodically whether normal or not)
LED SHORT	LEDx	LEDx > 5V	н	After LED_OK	LEDx < 5V	2 ¹² count	Immediately Auto-Restart after detection (Judge periodically whether normal or not)
LED GND SHORT	LEDx	LEDx < 0.2V and SSFB > 4.0V	н	-	LEDx > 0.2V or SSFB < 3.6V	(2 ¹² +2 ⁷) count	Latch
ISET	ISET	Under			Above	Immediately	Auto-Restart
GND SHORT	1311	ISET×90%	-	-	ISET×90%	Detect	
REG58 UVLO	REG58	REG58<2.4V	-	-	REG58>2.6V	Immediately Detect	Auto-Restart
VCC UVLO	VCC	VCC<7.3V	-	-	VCC>7.5V	Immediately Detect	Auto-Restart
OVP	OVP	OVP>3.0V	-	-	OVP<2.9V	Immediately Detect	Auto-Restart
SCP	OVP	OVP<0.1V	-	-	OVP>0.1V	2 ¹² count	Auto-Restart
ОСР	CS	OCP>0.45V	-	-	-	Immediately Detect	Pulse-by-Pulse

To clear the latch type, STB should be set to "L" once, and then to "H".

Drotostion Eurotian	Operation after the protection function detected				
Protection Function	DC/DC	LED Driver	Soft-start		
LED OPEN Continue to operate		Only detected LED ch stops after CP count	Continue to operate		
LED SHORT	LED SHORT Continue to operate		Continue to operate		
LED GND SHORT	Stop after (CP+27) countOnly detected LED ch stops after CP countOther LED ch stop operation after (CP+27) count		Discharge after (CP+2 ⁷) count		
ISET GND SHORT	Stop immediately	Stop immediately	Continue to operate		
STB Stop immediately		Stop (and when REG58<2.4V)	Discharge immediately		
REG58 UVLO	Stop immediately	Stop immediately	Discharge immediately		
VCC UVLO	Stop immediately	Stop immediately	Discharge immediately		
OVP Stop immediately (N pin only)		Continue to operate	Continue to operate		
SCP Stop immediately (N pin only)		Stop after CP count	Discharge after CP count		
OCP	N pin limits DUTY	Continue to operate	Continue to operate		

* CP= 20ms (RT=75KΩ)

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the Pd stated in this specification is when the IC is mounted on a 70mm x 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the Pd rating.

6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

7. Rush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes – continued

10. Unused Input Terminals

Input terminals of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input terminals should be connected to the power supply or ground line.

11. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

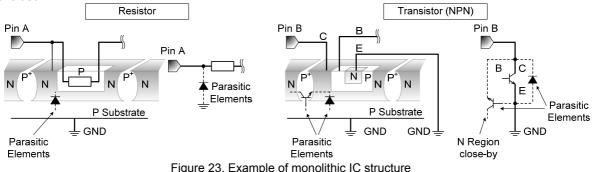


Figure 23. Example of monolithic IC st

12. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

13. Area of Safe Operation (ASO)

Operate the IC such that the output voltage, output current, and power dissipation are all within the Area of Safe Operation (ASO).

14. Thermal Shutdown Circuit(TSD)

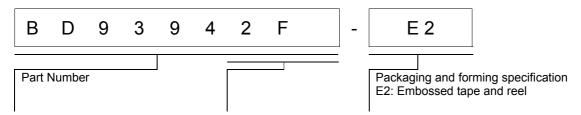
This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF all output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

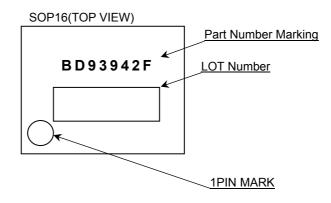
15. Over Current Protection Circuit (OCP)

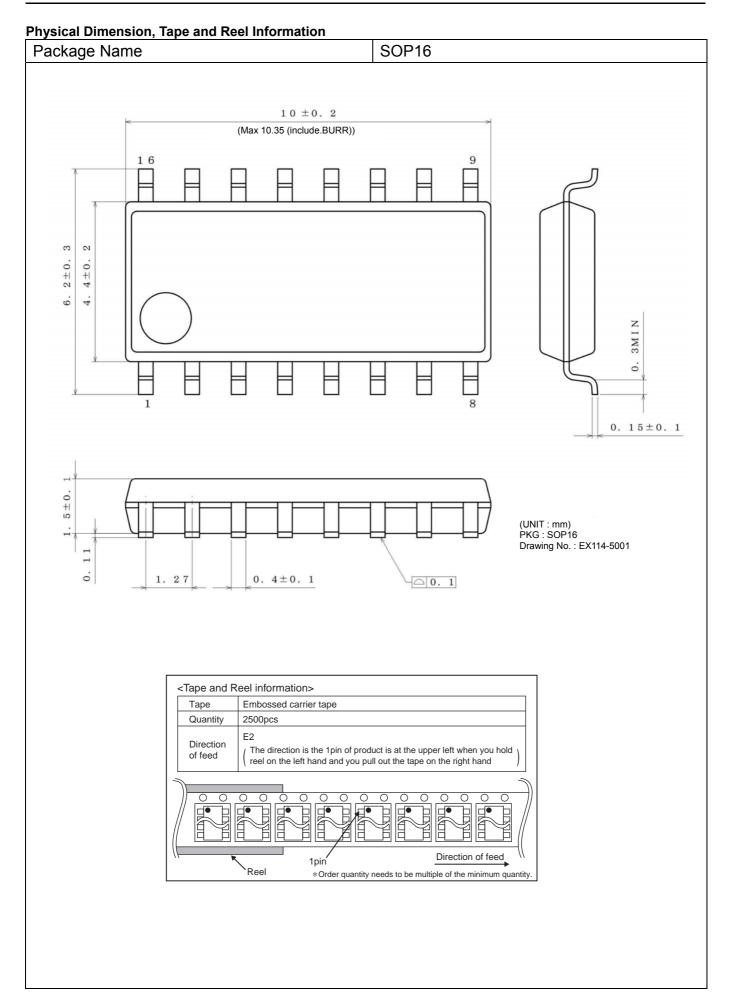
This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

Ordering Information



Marking Diagrams





Revision History

Date	Revision	Changes	
12.Feb.2015	001	New release	
12.Aug.2015	002	p.3 [REG58 Block] Soft start completion voltage -> REG58 available current	

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CLASSⅣ	CLASSII	CLASSⅢ	CLASSI

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 - [C] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж: moschip.ru moschip.ru_4

moschip.ru_6 moschip.ru_9